

December 2013

74LCX11 Low Voltage Triple 3-Input AND Gate with 5V Tolerant Inputs

Features

- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 6.0ns t_{PD} max. (V_{CC} = 3.3V), 10µA I_{CC} max.
- Power down high impedance inputs and outputs
- ±24mA output drive (V_{CC} = 3.0V)
- Implements proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds JEDEC 78 conditions
- ESD performance:
- Human body model > 2000V
- Machine model > 200V
- Leadless DQFN package

General Description

The LCX11 is a triple 3-input AND gate with buffered outputs. LCX devices are designed for low voltage (2.5V or 3.3V) operation with the added capability of interfacing to a 5V signal environment.

The 74LCX11 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Ordering Information

Order Number	Package Number	Package Description			
74LCX11M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
74LCX11SJ	M14D	4-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
74LCX11BQX ⁽¹⁾	MLP14A	14-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 3.0mm			
74LCX11MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			

Note:

1. DQFN package available in Tape and Reel only.

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagrams Logic Symbol Pin Assignments for SOIC, SOP, and TSSOP IEEE/IEC & A_0 14 V_{CC} A_0 13 С₀ B₀ B₀ 00 12 00 A_1 С₀ 11 Α2 В₁ 10 C₁ B₂ A₁ 9 6 C₂ 01 8 B₁ 01 7 02 GND C_1 (Top View) A_2 Pad Assignments for DQFN B₂ 02 A₀ V_{CC} 14 1 C₂ (14) 1 13 2 (13 C₀ B₀ 2 (12 A₁ 00 3 D (11 B₁ 4 A₂ A Logic Diagram C1 Ρ (10 5 B₂ 01 6 9 C₂ 9 6 7 8 В GND O2 8 7 (Bottom View) С (Top Through View) **Pin Description Pin Names** Description A_n, B_n, C_n Inputs Outputs On DAP No Connect Note: DAP (Die Attach Pad)

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
VI	DC Input Voltage	-0.5V to +7.0V
Vo	DC Output Voltage, Output in HIGH or LOW State ⁽²⁾	–0.5V to V _{CC} + 0.5V
I _{IK}	DC Input Diode Current, V _I < GND	–50mA
I _{OK}	DC Output Diode Current	
	V _O < GND	–50mA
	V _O > V _{CC}	+50mA
Ι _Ο	DC Output Source/Sink Current	±50mA
I _{CC}	DC Supply Current per Supply Pin	±100mA
I _{GND}	DC Ground Current per Ground Pin	±100mA
T _{STG}	Storage Temperature	–65°C to +150°C

Note:

2. I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions⁽³⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage			
	Operating	2.0	3.6	V
	Data Retention	1.5	3.6	
VI	Input Voltage	0	5.5	V
Vo	Output Voltage, HIGH or LOW State	0	V _{CC}	V
I _{OH} / I _{OL}	Output Current			
	$V_{CC} = 3.0V - 3.6V$		±24	mA
	$V_{CC} = 2.7V - 3.0V$		±12	
	$V_{CC} = 2.3V - 2.7V$		±8	
T _A	Free-Air Operating Temperature	-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$, $V_{CC} = 3.0V$	0	10	ns/V

Note:

3. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

				T _A = -40°C to +85°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Min.	Max.	Units
VIH	HIGH Level Input Voltage	2.3–2.7		1.7		V
		2.7–3.6		2.0		
V _{IL}	LOW Level Input Voltage	2.3–2.7			0.7	V
		2.7–3.6			0.8	
V _{OH}	HIGH Level Output Voltage	2.3–3.6	$I_{OH} = -100 \mu A$	V _{CC} - 0.2		V
		2.3	$I_{OH} = -8mA$	1.8		
		2.7	$I_{OH} = -12mA$	2.2		
		3.0	$I_{OH} = -18 \text{mA}$	2.4		
			$I_{OH} = -24mA$	2.2		
V _{OL}	LOW Level Output Voltage	2.3–3.6	I _{OL} = 100μA		0.2	V
		2.3	$I_{OL} = 8 mA$		0.6	
		2.7	$I_{OL} = 12mA$		0.4	
		3.0	I _{OL} = 16mA		0.4	
			$I_{OL} = 24mA$		0.55	
I _I	Input Leakage Current	2.3–3.6	$0 \le V_I \le 5.5V$		±5.0	μA
I _{OFF}	Power-Off Leakage Current	0	$V_{\rm I}$ or $V_{\rm O} = 5.5 V$		10	μA
I _{CC}	Quiescent Supply Current	2.3–3.6	$V_{I} = V_{CC}$ or GND		10	μA
			$3.6V \le V_I \le 5.5V$		±10	
ΔI_{CC}	Increase in I _{CC} per Input	2.3–3.6	$V_{IH} = V_{CC} - 0.6V$		500	μA

AC Electrical Characteristics

		$T_A = -40^{\circ}C$ to +85°C, $R_L = 500\Omega$						
		$\label{eq:V_CC} \begin{split} V_{CC} &= 3.3V \pm 0.3V, \\ C_L &= 50 p F \end{split}$		$\begin{array}{c} \textbf{V}_{\textbf{CC}} = \textbf{2.7V},\\ \textbf{C}_{\textbf{L}} = \textbf{50pF} \end{array}$		$V_{CC} = 2.5V \pm 0.2V,$ $C_L = 30pF$		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PHL} , t _{PLH}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t _{OSHL} , t _{OSLH}	Output to Output Skew ⁽⁴⁾		1.0					ns

Note:

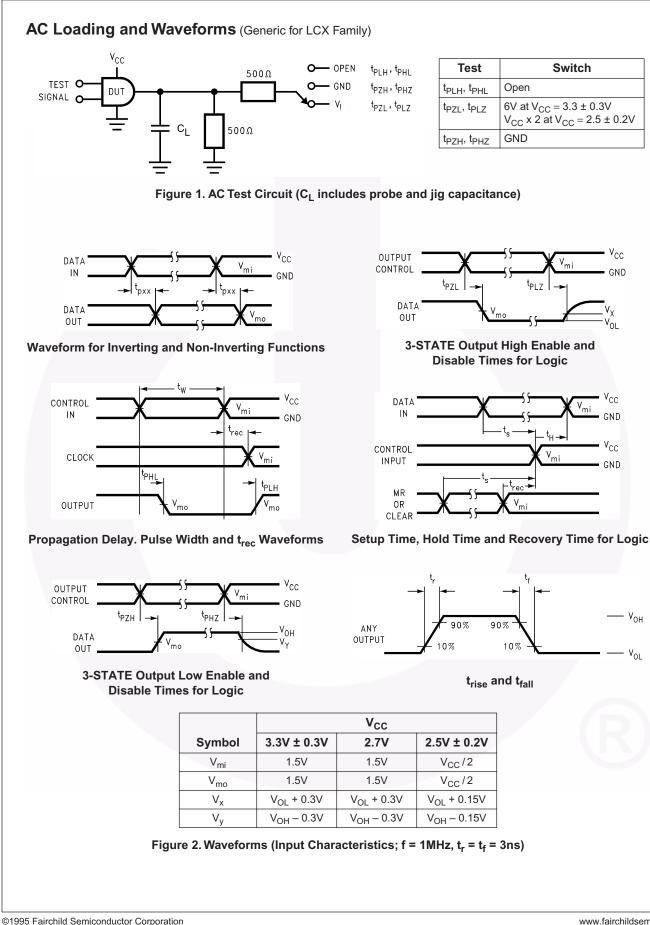
4. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

				$T_A = 25^{\circ}C$	
Symbol	Parameter	V _{CC} (V)	Conditions	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	$C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V$	0.8	V
		2.5	$C_L = 30 pF$, $V_{IH} = 2.5 V$, $V_{IL} = 0 V$	0.6	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	$C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V$	-0.8	V
		2.5	$C_{L} = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V$	-0.6	

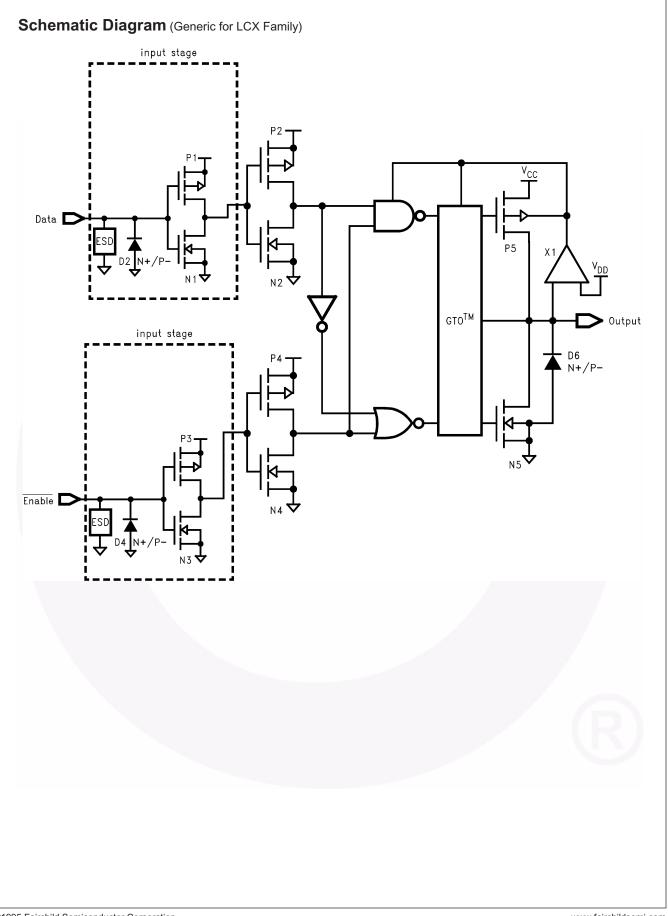
Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3$ V, $V_I = 0$ V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10MHz	25	pF



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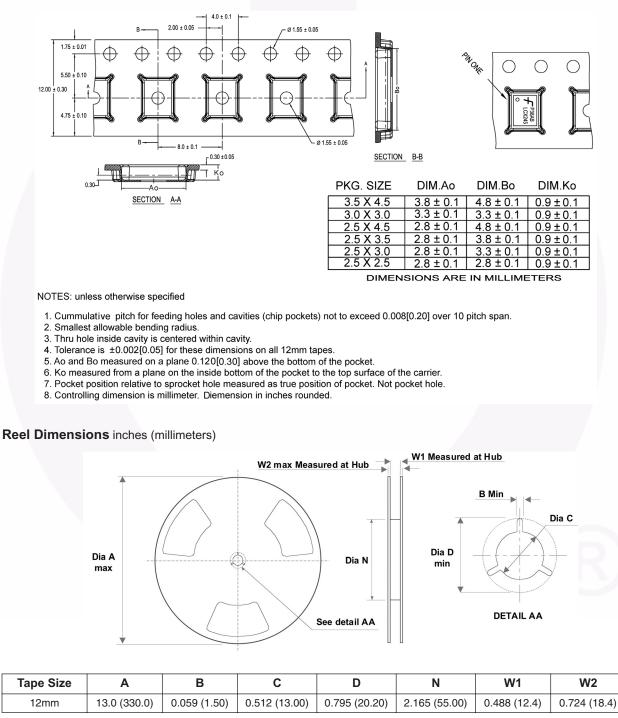
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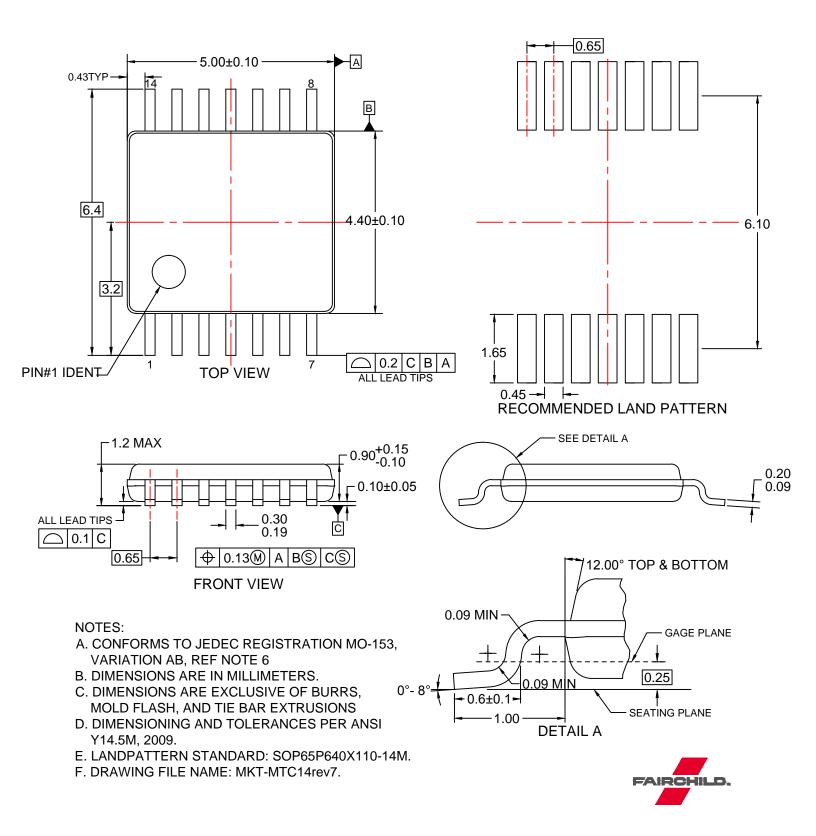
Tape and Reel Specification

Tape Format for DQFN

Package Designator	Tape Section	Number of Cavities	Cavity Status	Cover Tape Status	
BQX	Leader (Start End)	125 (Тур.)	Empty	Sealed	
	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (Тур.)	Empty	Sealed	

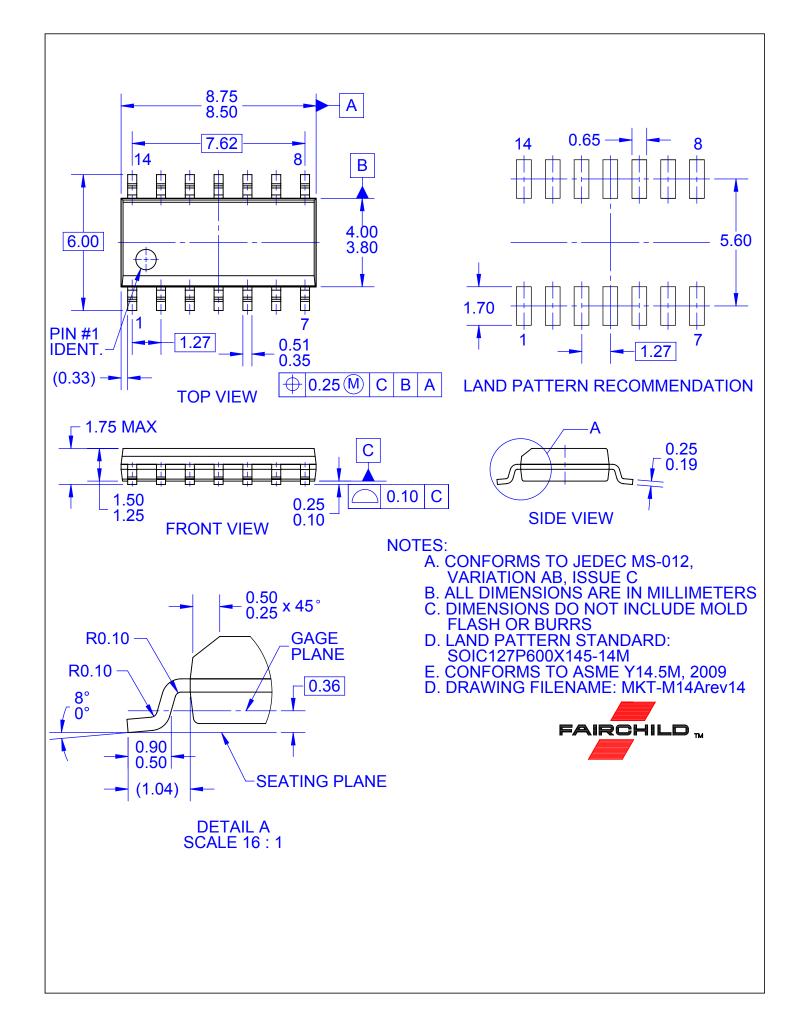
Tape Dimensions inches (millimeters)

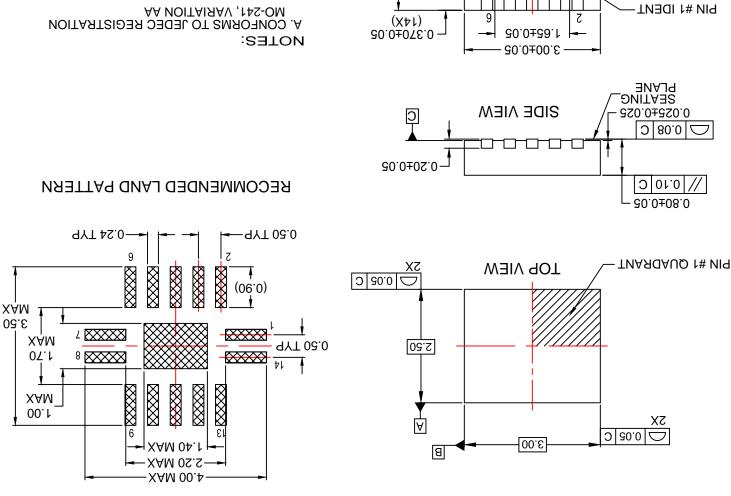




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BOTTOM VIEW

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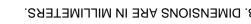
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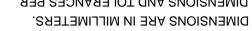
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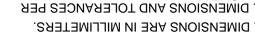
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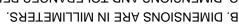
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- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.











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